

## 3V-40V Vin, 500mA, Ultra-Low Quiescent Current LDO with Power-Good

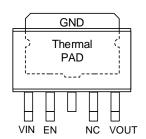


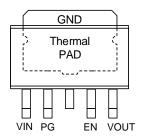
Release to production( ).
Update the ELECTRICAL CHARACTERISTICS.

	5A00Q	
	F50BQ	
	F33BQ	
	5F50Q	
	5F33Q	
	F50AQ	













(1) (2)



PARAMETER (4-layer)		UNIT
R JA_EVM		
PARAMETER (4-layer)		UNIT
R JA_EVM		

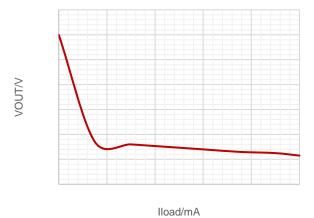
(2)

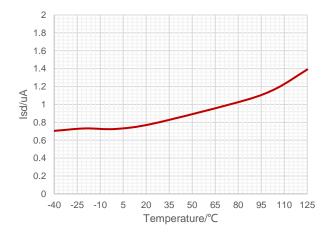
(3)

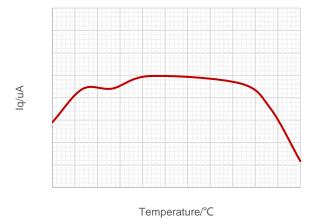


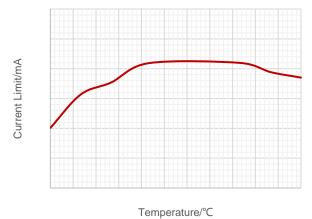




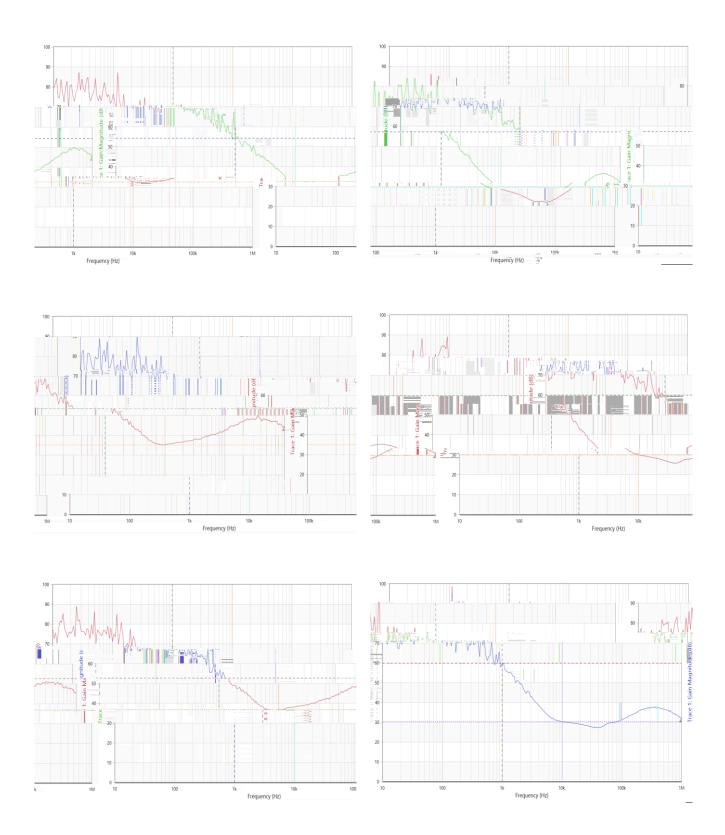





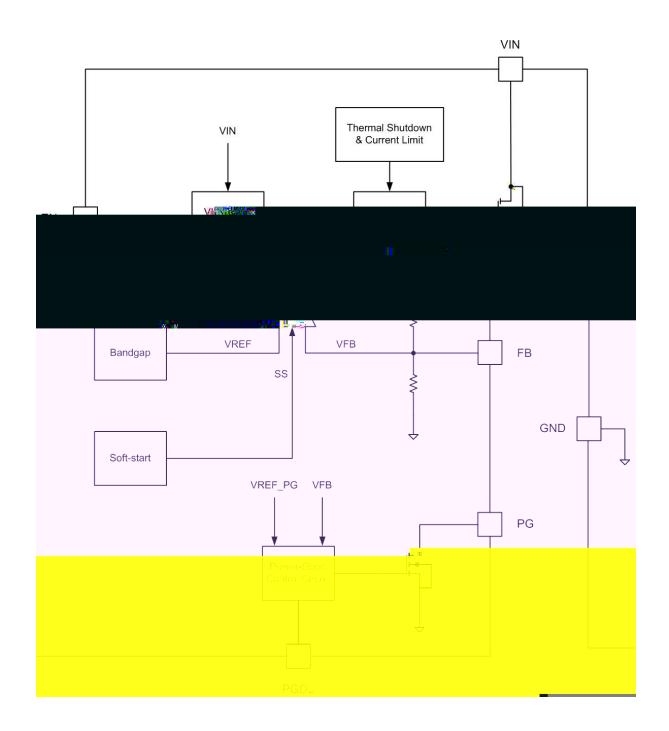






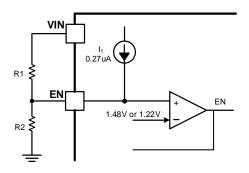






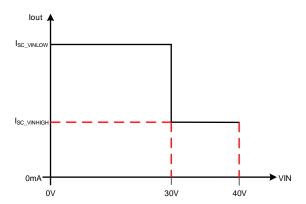


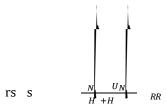
$$r$$
 DM  $G$  DM  $\frac{1}{1}$ 



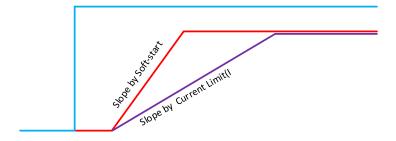


## VIN\_HIGH Control







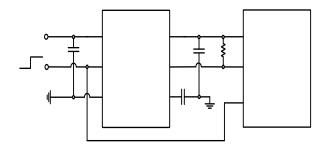


$$O C \frac{s_{OFC} \quad H_{OFC}}{U_{OFC}}$$

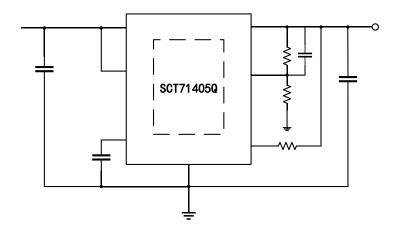
о с

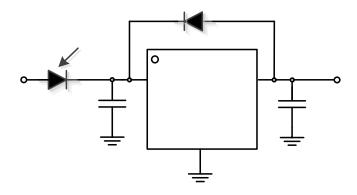
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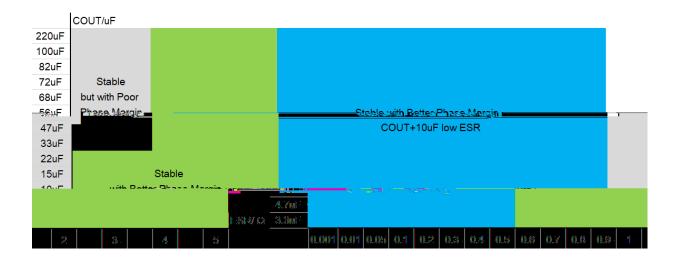






 $\frac{U_N}{U_{DE}}$  1





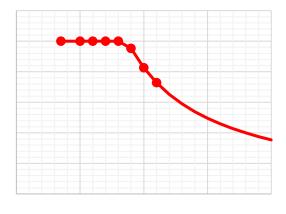
C HM NTS NTS HM MC

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VIN/V

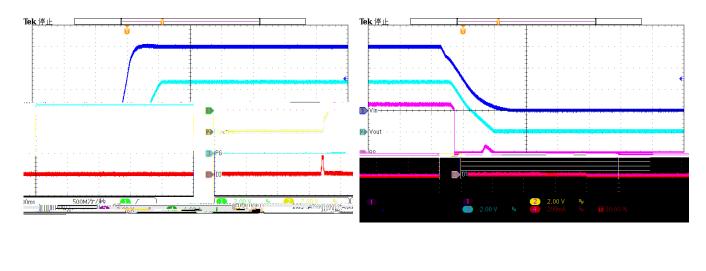


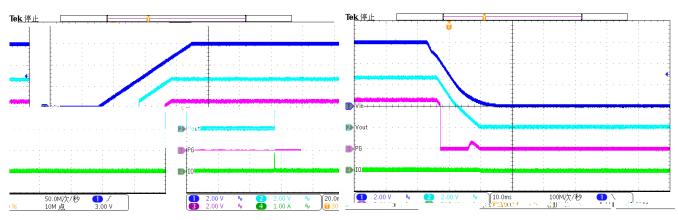
 $\leq$ 

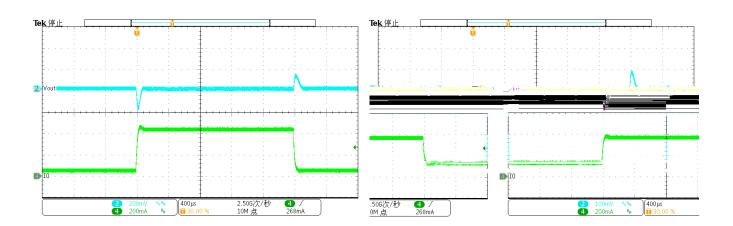
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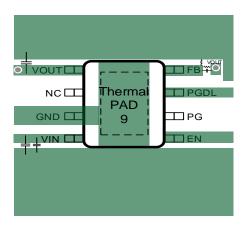
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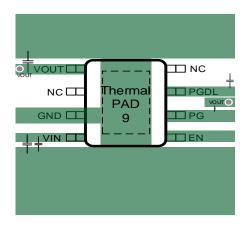
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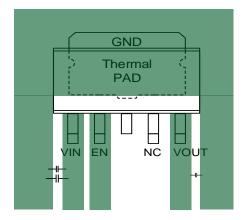
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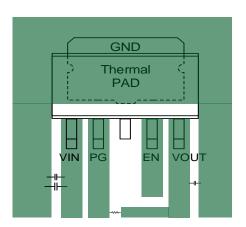
4.

5.

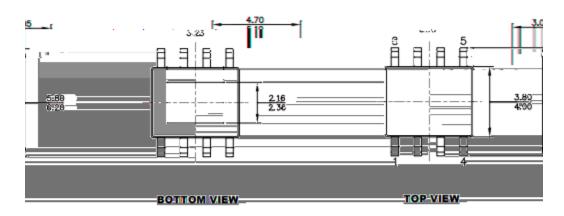


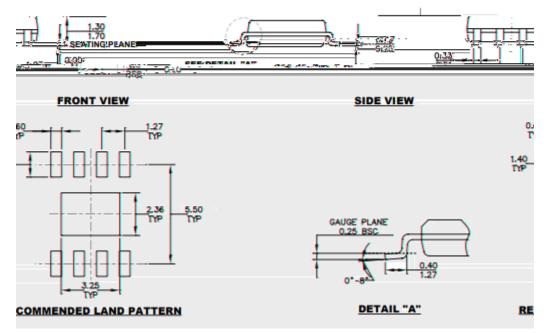








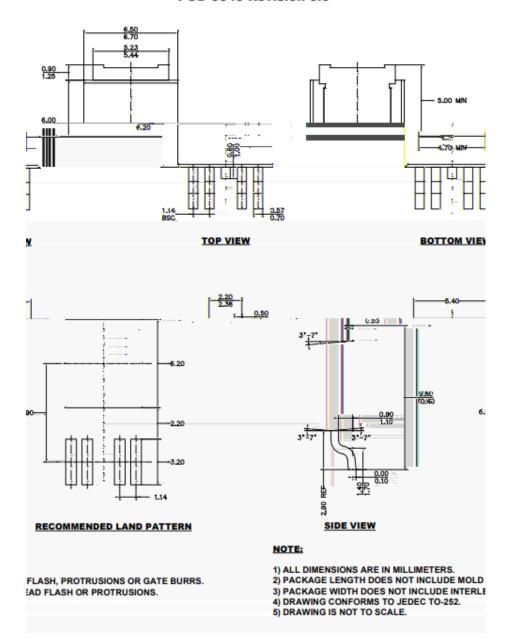








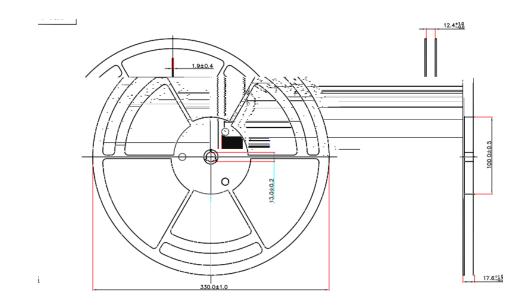
## PACKAGE OUTLINE DRAWING FOR TO252-4L POD-0040 Revision 0.0

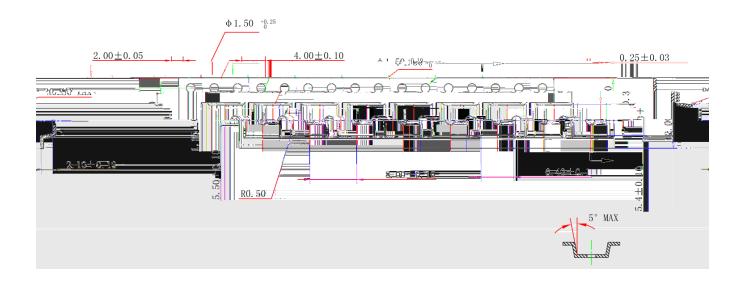












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